

S10226-10

Small, resin-sealed CMOS image sensor

The S10226-10 is a resin-sealed CMOS linear image sensor to offer compact size and high cost-performance compared to our previous product (S9226 series).

Features

- **Compact and high cost-performance**
Surface mount type package: 2.4 × 9.1 × 1.6^t mm
- **Pixel pitch: 7.8 μm**
Pixel height: 125 μm
- **1024 pixels**
- **Single 3.3 V power supply operation**
- **High sensitivity, low dark current, low noise**
- **On-chip charge amplifier with excellent input/output characteristics**
- **Built-in timing generator allows operation with only Start and Clock pulse inputs.**
- **Video data rate: 200 kHz max.**
- **Spectral response range: 400 to 1000 nm**

Applications

- **Barcode readers**
- **Displacement meters**
- **Refractometers**
- **Interferometers**
- **Miniature spectrometers**

Structure

Parameter	Specification	Unit
Number of pixels	1024	-
Pixel pitch	7.8	μm
Pixel height	125	μm
Photosensitive area length	7.9872	mm
Package	Glass epoxy	-
Seal material	Silicone resin	-

Absolute maximum ratings

Parameter	Symbol	Condition	Value	Unit
Supply voltage	V _{dd}	T _a =25 °C	-0.3 to +6	V
Gain selection terminal voltage	V _g	T _a =25 °C	-0.3 to +6	V
Clock pulse voltage	V(CLK)	T _a =25 °C	-0.3 to +6	V
Start pulse voltage	V(ST)	T _a =25 °C	-0.3 to +6	V
Operating temperature*1	T _{opr}		-25 to +85	°C
Storage temperature*1	T _{stg}		-25 to +85	°C
Reflow soldering conditions*2	T _{sol}		Peak temperature 260 °C, 3 times (See P.7)	-

*1: No condensation

*2: JEDEC level 2a

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

Recommended terminal voltage (Ta=25 °C)

Parameter	Symbol	Min.	Typ.	Max.	Unit
Supply voltage	Vdd	3.3	5	5.25	V
Gain selection terminal voltage	High gain	0	-	0.4	V
	Low gain	Vdd - 0.25	Vdd	Vdd + 0.25	V
Clock pulse voltage	High level	Vdd - 0.25	Vdd	Vdd + 0.25	V
	Low level	0	-	0.4	V
Start pulse voltage	High level	Vdd - 0.25	Vdd	Vdd + 0.25	V
	Low level	0	-	0.4	V

Electrical characteristics [Ta=25 °C, Vdd=5 V, V(CLK)=V(ST)=5 V]

Parameter	Symbol	Min.	Typ.	Max.	Unit
Clock pulse frequency	f(CLK)	100	-	800	kHz
Video data rate	VR	-	f(CLK)/4	-	kHz
Current consumption	Vdd=5 V	-	5	8	mA
	Vdd=3.3 V	-	4.5	7	

Electrical and optical characteristics [Ta=25 °C, f(CLK)=800 kHz, Vdd=5 V: V(CLK)=V(ST)=5 V, Vdd=3.3 V: V(CLK)=V(ST)=3.3 V]

Parameter	Symbol	Min.	Typ.	Max.	Unit
Spectral response range	λ	400 to 1000			nm
Peak sensitivity wavelength	λ_p	-	700	-	nm
Dark output voltage*3	Vdd=5 V	High gain	-	0.8	mV
		Low gain	-	0.4	
	Vdd=3.3 V	High gain	-	0.5	
		Low gain	-	0.25	
Saturation output voltage	Vdd=5 V	2.6	3.2	-	V
	Vdd=3.3 V	1.4	2.0	-	
Readout noise	High gain	-	1.4	2.2	mV rms
	Low gain	-	0.7	1.1	
Output offset voltage	Vo	0.2	0.4	0.6	V
Photoresponse nonuniformity*4 *5	PRNU	-	-	±8.5	%

*3: Integration time=10 ms

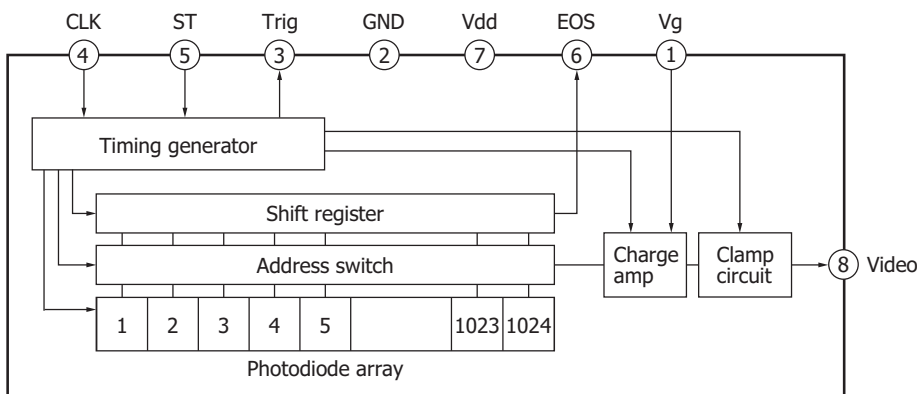
*4: Photoresponse nonuniformity (PRNU) is the output nonuniformity that occurs when the entire photosensitive area is uniformly illuminated by light which is 50% of the saturation exposure level. PRNU is measured using 1022 pixels excluding the pixels at both ends, and is defined as follows:

$$PRNU = \frac{\Delta X}{X} \times 100 (\%)$$

X: average output of 1022 pixels excluding the pixels at both ends, ΔX : difference between X and maximum or minimum output

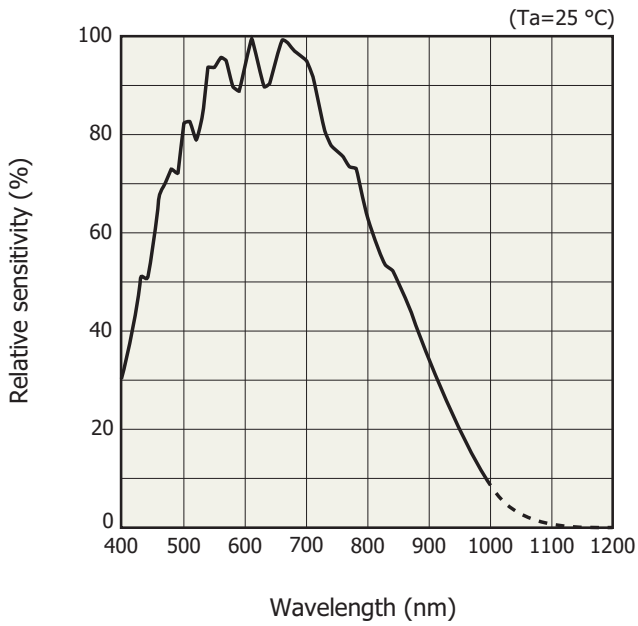
*5: Measured with a tungsten lamp of 2856 K

Block diagram



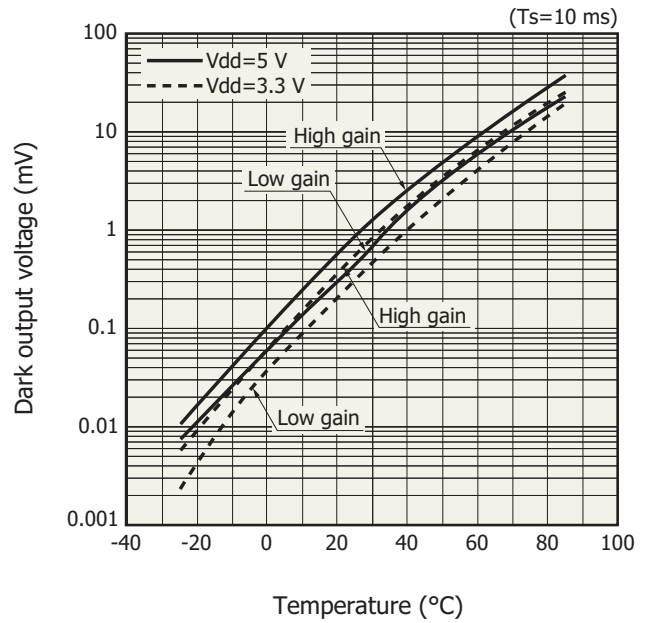
KMPDC0165ED

Spectral response (typical example)



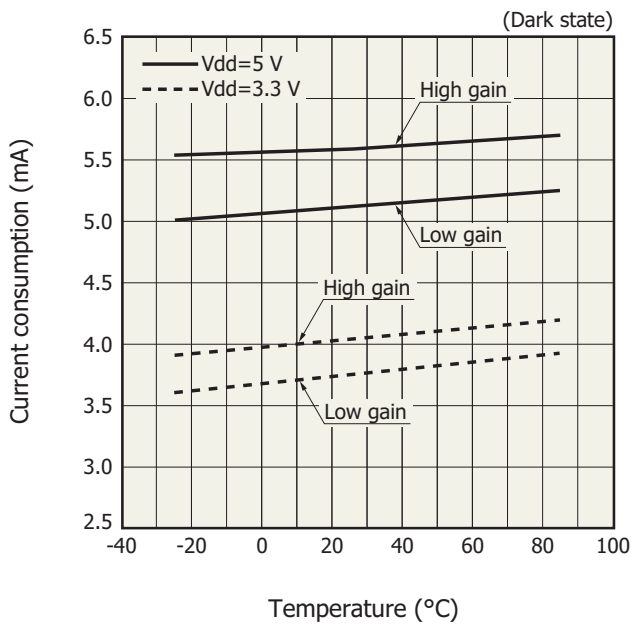
KMPD80417EA

Dark output voltage vs. temperature (typical example)



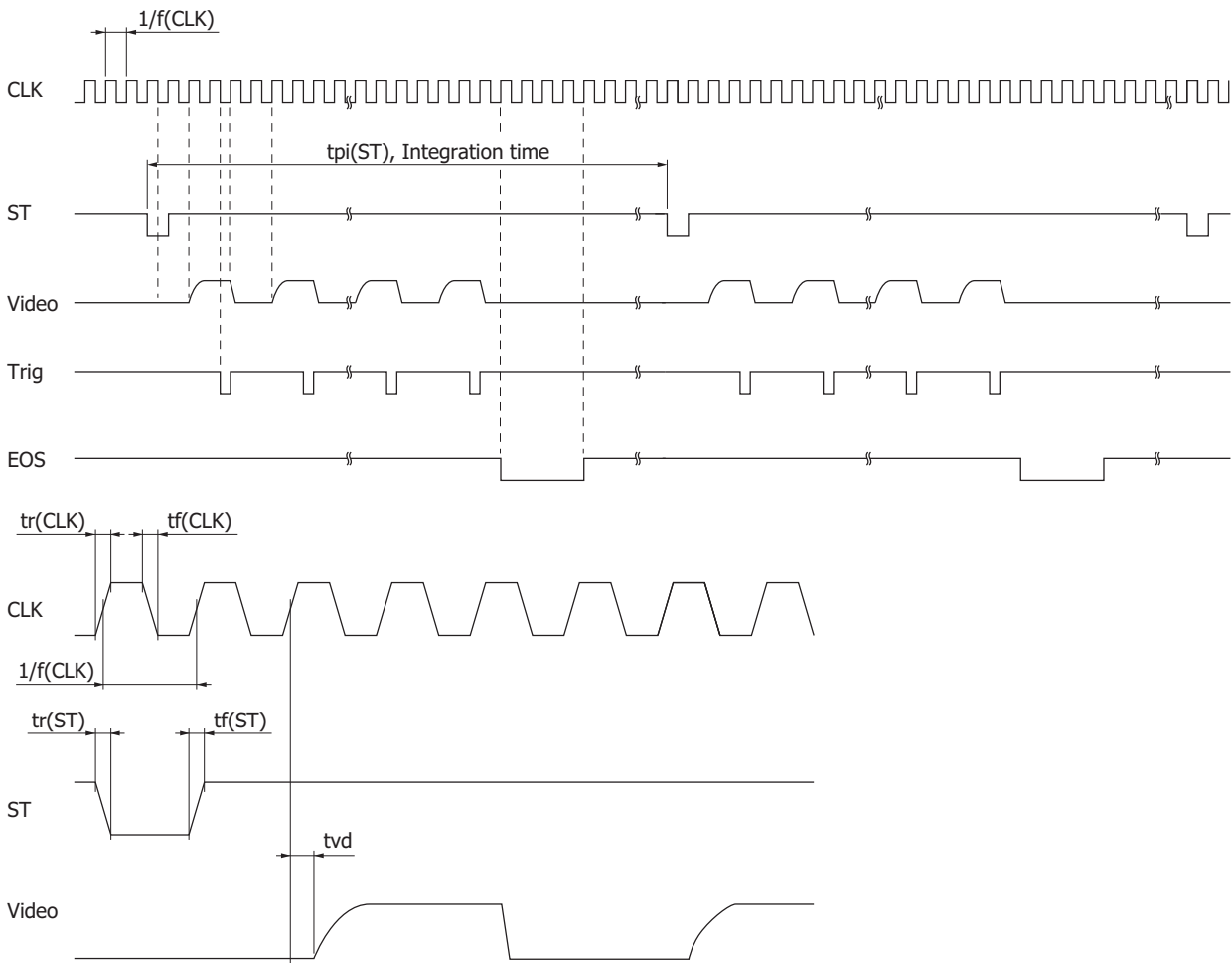
KMPD80259EB

Current consumption vs. temperature (typical example)



KMPD80260EB

Timing chart



KMPD0164EC

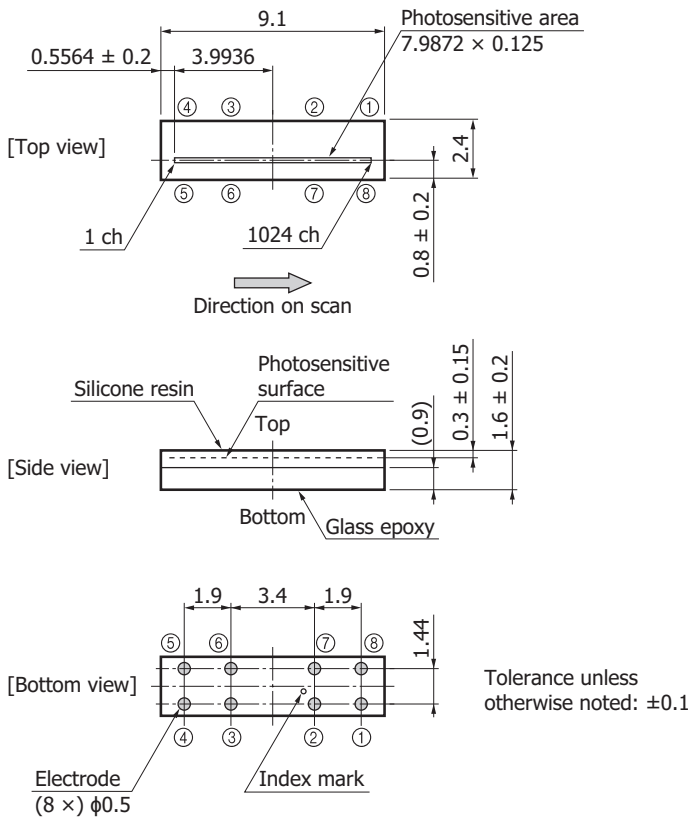
Parameter	Symbol	Min.	Typ.	Max.	Unit
Start pulse interval	$t_{pi}(\text{ST})$	$4104/f(\text{CLK})$	-	-	s
Start pulse rise and fall times	$t_r(\text{ST}), t_f(\text{ST})$	0	20	30	ns
Clock pulse duty ratio	-	40	50	60	%
Clock pulse rise and fall times	$t_r(\text{CLK}), t_f(\text{CLK})$	0	20	30	ns
Video delay time*6	t_{vd}	10	20	30	ns

*6: $T_a=25\text{ }^\circ\text{C}$, $V_{dd}=5\text{ V}$, $V(\text{CLK})=V(\text{ST})=5\text{ V}$

Note: The CLK pulse should be set from high to low just once when the ST pulse is low. The internal shift register starts operating at this timing.

The storage time is determined by the start pulse intervals. However, since the charge storage of each pixel is carried out between the signal readout of that pixel and the next signal readout of the same pixel, the start time of charge storage differs depending on each pixel. In addition, the next start pulse cannot be input until signal readout from all pixels is completed.

Dimensional outline (unit: mm)

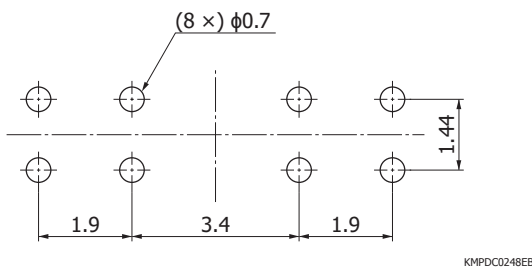


KMPDA0315EB

Pin connections

Pin no.	Name	I/O	Description
1	Vg	I	Gain selection; low gain: Vdd or open, high gain: GND
2	GND	-	Ground
3	Trig	O	Trigger: timing signal output for A/D converter
4	CLK	I	Clock pulse (pulse for synchronizing the internally generated pulses that control sensor operation frequency)
5	ST	I	Start pulse (pulse for initializing the internally generated pulses that set the timing to start reading pixel signals)
6	EOS	O	End of scan (shift register end-of-scan signal pulse generated after reading signals from all pixels)
7	Vdd	I	Power supply voltage
8	Video	O	Video signal output

Recommended land pattern (unit: mm)



Appearance inspection standards

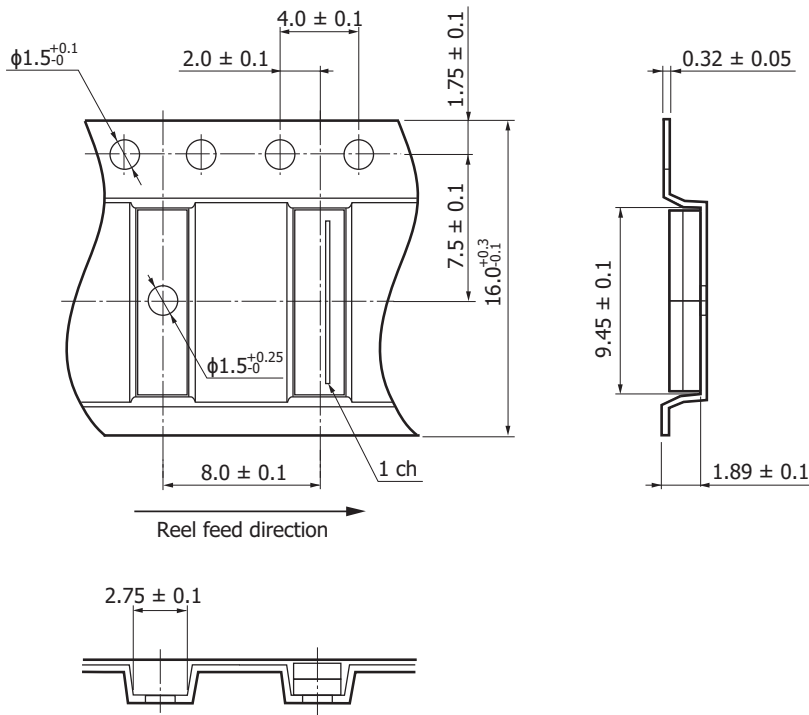
Parameter	Test criterion	Inspection method
Foreign matter on photosensitive area	10 μm max.	Automated camera

Standard packing specifications

- Reel (conforms to JEITA ET-7200)

Dimensions	Hub diameter	Tape width	Material	Electrostatic characteristic
330 mm	100 mm	16 mm	PPE	Conductive

- Embossed tape (unit: mm, material: polycarbonete resin, conductive)

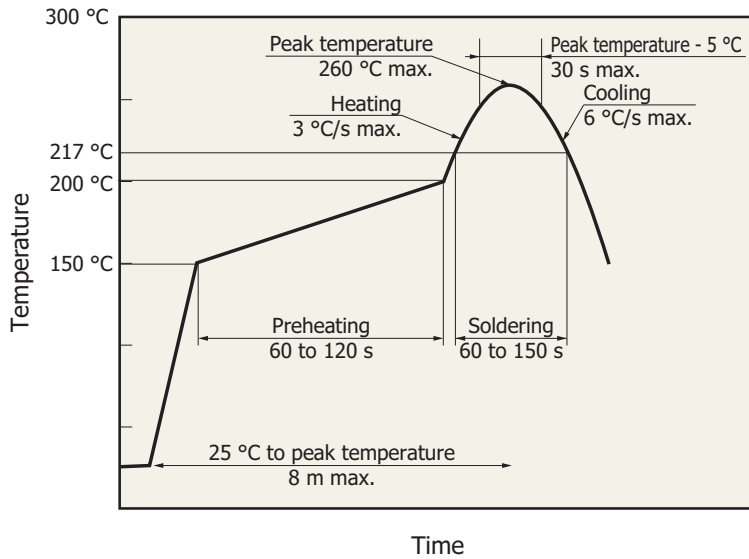


KMPDC0433EA

- Packing quantity
2000 pcs/reel

- Packing type
Reel and desiccant in moisture-proof packing (vaccum-sealed)

Recommended temperature profile for reflow soldering (typical example)



- This product supports lead-free soldering. After unpacking, store it in an environment at a temperature of 30 °C or less and a humidity of 60% or less, and perform soldering within 4 weeks.
- The effect that the product receives during reflow soldering varies depending on the circuit board and reflow oven that are used. Before actual reflow soldering, check for any problems by testing out the reflow soldering methods in advance.
- When three or more months have passed or if the packing bag has not been stored in an environment described above, perform baking. For the baking method, see the related information "Resin sealed type CMOS linear image sensor / Precautions."

Precautions

(1) Electrostatic countermeasures

- This device has a built-in protection circuit as a safeguard against static electrical charges. However, to prevent destroying the device with electrostatic charges, take countermeasures such as grounding yourself, the workbench and tools.
- Protect this device from surge voltages which might be caused by peripheral equipment.

(2) Package handling

- The photosensitive area of this device is sealed and protected by transparent resin. When compared to a glass faceplate, the surface of transparent resin may be less uniform and is more likely to be scratched. Be very careful when handling this device and also when designing the optical systems.
- Dust or grime on the light input window might cause nonuniform sensitivity. To remove dust or grime, blow it off with compressed air.

(3) Surface protective tape

- Protective tape is affixed to the surface of this product to protect the photosensitive area. After assembling the product, remove the tape before use.

(4) Operating and storage environments

- Handle the device within the temperature range specified in the absolute maximum ratings. Operating or storing the device at an excessively high temperature and humidity may cause variations in performance characteristics and must be avoided.

(5) UV exposure

- This product is not designed to prevent deterioration of characteristics caused by UV exposure, so do not expose it to UV light.

Related information

www.hamamatsu.com/sp/ssd/doc_en.html

■ Precautions

- Notice
- Image sensor / Precautions
- Resin-sealed CMOS linear image sensors / Precautions

Information described in this material is current as of July, 2014.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

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HAMAMATSU

www.hamamatsu.com

HAMAMATSU PHOTONICS K.K., Solid State Division

1126-1 Ichino-cho, Higashi-ku, Hamamatsu City, 435-8558 Japan, Telephone: (81) 53-434-3311, Fax: (81) 53-434-5184

U.S.A.: Hamamatsu Corporation: 360 Foothill Road, Bridgewater, N.J. 08807, U.S.A., Telephone: (1) 908-231-0960, Fax: (1) 908-231-1218

Germany: Hamamatsu Photonics Deutschland GmbH: Arzbergerstr. 10, D-82211 Herrsching am Ammersee, Germany, Telephone: (49) 8152-375-0, Fax: (49) 8152-265-8

France: Hamamatsu Photonics France S.A.R.L.: 19, Rue du Saule Trapu, Parc du Moulin de Massy, 91882 Massy Cedex, France, Telephone: 33-(1) 69 53 71 00, Fax: 33-(1) 69 53 71 10

United Kingdom: Hamamatsu Photonics UK Limited: 2 Howard Court, 10 Tewin Road, Welwyn Garden City, Hertfordshire AL7 1BW, United Kingdom, Telephone: (44) 1707-294888, Fax: (44) 1707-325777

North Europe: Hamamatsu Photonics Norden AB: Torshamnsgatan 35 16440 Kista, Sweden, Telephone: (46) 8-509-031-00, Fax: (46) 8-509-031-01

Italy: Hamamatsu Photonics Italia S.r.l.: Strada della Moia, 1 int. 6, 20020 Arese (Milano), Italy, Telephone: (39) 02-93581733, Fax: (39) 02-93581741

China: Hamamatsu Photonics (China) Co., Ltd.: B1201, Jiaming Center, No.27 Dongsanhuan Beilu, Chaoyang District, Beijing 100020, China, Telephone: (86) 10-6586-6006, Fax: (86) 10-6586-2866